



SiC SCHOTTKY DIODE TYPE 2×100A

Features

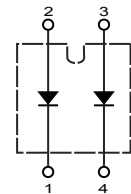
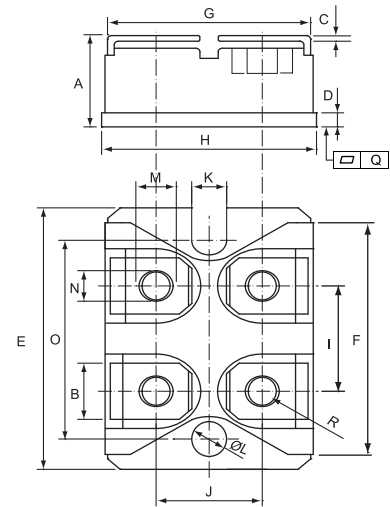
- High surge current capable
- Zero reverse recovery current
- High bandwidth
- Isolation type package
- Temperature Independent Switching Behavior
- VDC 650 V
- I_F (T_C<135°C) 2×100 A

Benefits

- Unipolar rectifier
- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Parallel devices without thermal runaway

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment
- Power factor correction
- Diode snubber
- Automotive
- induction heating



CSRI 2X100 - XXX

Maximum Ratings

Operating Junction Temperature : - 55 °C to +175 °C

Storage Temperature : -55 °C to +175 °C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×100-065	650V	650V

Maximum Rating	Symbol	Conditions	Value	Unit
Continuous forward current (per leg)	I _F	T _C =135 °C	100	A
Surge non-repetitive forward current sine halfwave (per leg)	I _{FSM}	T _C =25 °C, t _p =8.3 ms	800	
		T _C =150 °C, t _p =8.3 ms	500	
Non-repetitive peak forward current (per leg)	I _{F,max}	T _C =25 °C, t _p =10 μs	3200	
		T _C =150 °C, t _p =10 μs	2000	
Repetitive peak reverse voltage	V _{RRM}	T _J =25 °C	650	V
Isolation voltage	V _{iso}	50/60 Hz, RMS I _{ISOL} 1 ≤ mA	2500	V
Mounting torque		M4 Screw	1.3	N-m

	DIMENSIONS			
	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.460	0.483	11.68	12.28
B	0.307	0.323	7.80	8.20
C	0.030	0.033	0.75	0.85
D	0.071	0.081	1.80	2.05
E	1.488	1.504	37.80	38.20
F	1.248	1.260	31.70	32.00
G	0.917	0.957	23.30	24.30
H	0.996	1.008	25.30	25.60
I	0.579	0.602	14.70	15.30
J	0.492	0.516	12.50	13.10
K	-	0.169	-	4.30
L	-	0.169	-	4.30
M	0.181	0.197	4.60	5.00
N	0.165	0.181	4.20	4.60
O	1.181	1.197	30.00	30.40
Q	-0.002	0.004	-0.05	0.10
R	M4*8			



Electrical Characteristics, at $T_j=25\text{ }^\circ\text{C}$, unless otherwise specified. (per leg)

Static Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
DC blocking voltage	V_{DC}		650	-	-	V
Diode forward voltage	V_F	$I_F=100\text{A}, T_j=25\text{ }^\circ\text{C}$	-	1.45	1.65	
		$I_F=100\text{A}, T_j=175\text{ }^\circ\text{C}$	-	1.70	2.00	
Reverse current	I_R	$V_R=650\text{V}, T_j=25\text{ }^\circ\text{C}$	-	30	200	μA
		$V_R=650\text{V}, T_j=175\text{ }^\circ\text{C}$	-	200	1000	

AC Characteristics (per leg)

Static Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Total capacitive charge	Q_{rr}	$V_R=400\text{V}, T_j=25\text{ }^\circ\text{C}$	-	390	-	nC
Total capacitance	C	$V_R=0\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	7,040	-	pF
		$V_R=200\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	699	-	
		$V_R=400\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	654	-	

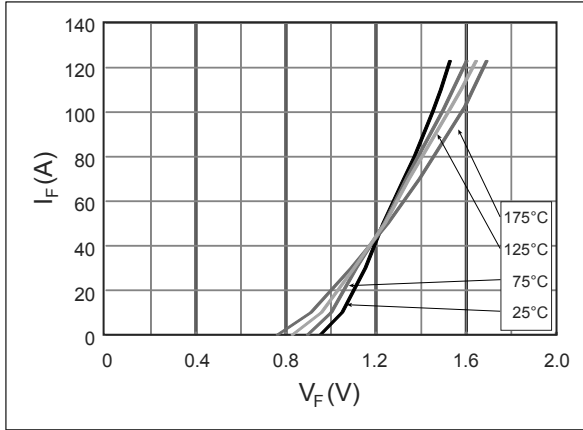
Thermal Characteristics (per leg)

Static Characteristics	Symbol	Values	Unit
		typ.	
Thermal resistance from junction to case	$R_{\theta JC}$	0.14	$^\circ\text{C/W}$

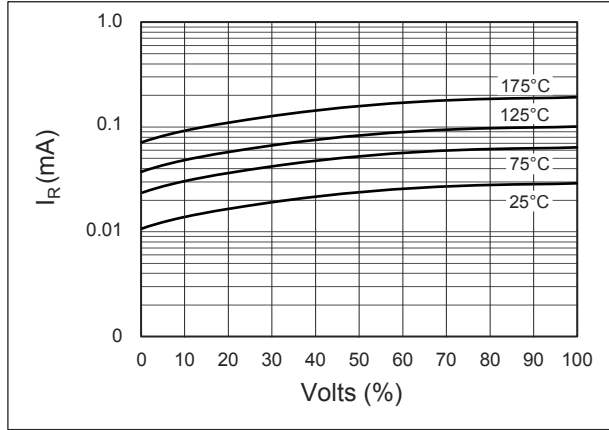


Typical Performance

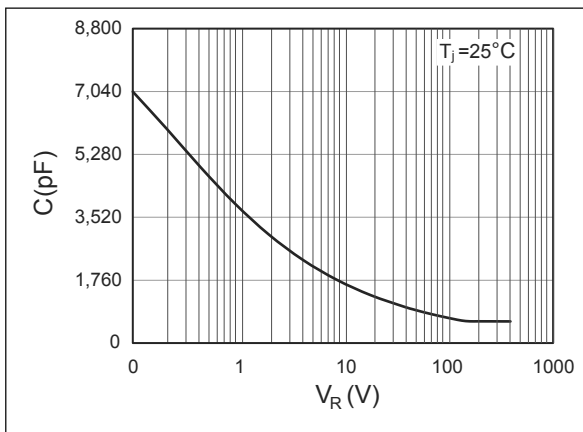
Forward Characteristics (parameterized on T_j)



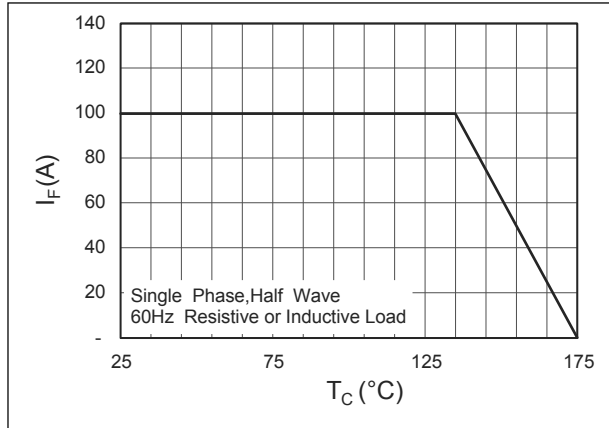
Reverse Characteristics (parameterized on T_j)



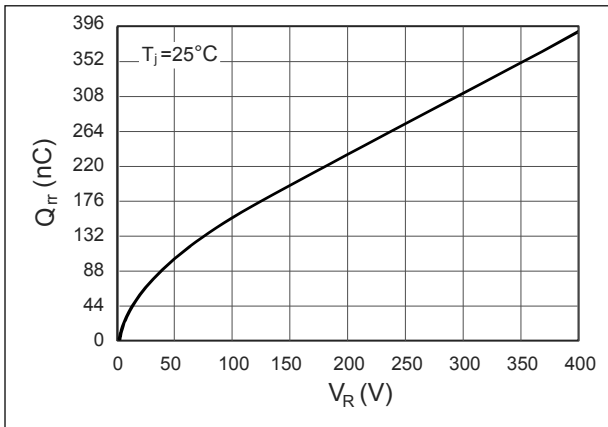
Capacitance



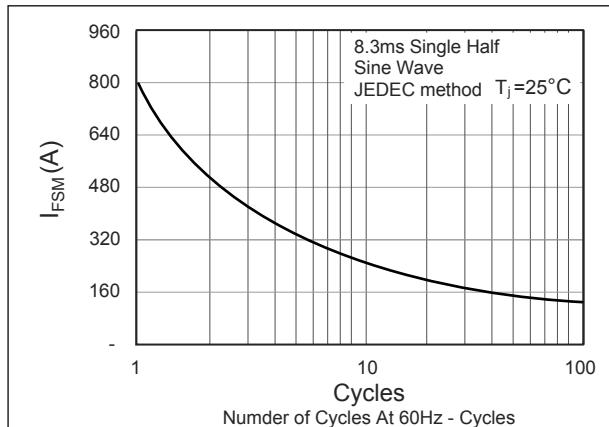
Current Derating



Recovery Charge



Forward Surge Current





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